PDTC143X series

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω

Rev. 10 — 16 November 2009

Product data sheet

1. Product profile

1.1 General description

NPN Resistor-Equipped Transistors (RET) family.

Table 1. Product overview

Type number	Package	PNP complement		
	NXP	JEITA	JEDEC	_
PDTC143XE	SOT416	SC-75	-	PDTA143XE
PDTC143XEF	SOT490	SC-89	-	PDTA143XEF
PDTC143XK	SOT346	SC-59A	TO-236	PDTA143XK
PDTC143XM	SOT883	SC-101	-	PDTA143XM
PDTC143XS[1]	SOT54	SC-43A	TO-92	PDTA143XS
PDTC143XT	SOT23	-	TO-236AB	PDTA143XT
PDTC143XU	SOT323	SC-70	-	PDTA143XU

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2).

1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- 100 mA output current capability
- Reduces component count
- Reduces pick and place costs

1.3 Applications

- Digital applications
- Controlling IC inputs

- Cost-saving alternative for BC847 series in digital applications
- Switching loads

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	50	V
Io	output current		-	-	100	mA
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		1.7	2.1	2.6	



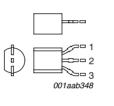
2. Pinning information

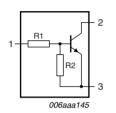
Table 3. Pinning

Pin	Description	Simplified outline Symbol
SOT54		
1	input (base)	
2	output (collector)	
3	GND (emitter)	001aab347 1 R1 R2 3

0	റ	т	6	Λ	Λ
9	U		J	77	H

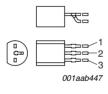
1	input (base)
2	output (collector)
3	GND (emitter)

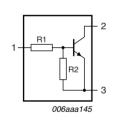




SOT54 variant

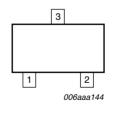
1	input (base)
2	output (collector)
3	GND (emitter)

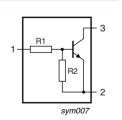




SOT23; SOT323; SOT346; SOT416; SOT490

1	input (base)
2	GND (emitter)
3	output (collector)

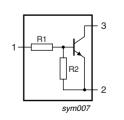




SOT883

1	input (base)
2	GND (emitter)
3	output (collector)





NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω

Ordering information 3.

Table 4. **Ordering information**

		Package					
	Name	Description	Version				
PDTC143XE	SC-75	plastic surface mounted package; 3 leads	SOT416				
PDTC143XEF	SC-89	plastic surface mounted package; 3 leads	SOT490				
PDTC143XK	SC-59A	plastic surface mounted package; 3 leads	SOT346				
PDTC143XM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm	SOT883				
PDTC143XS[1]	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54				
PDTC143XT	-	plastic surface mounted package; 3 leads	SOT23				
PDTC143XU	SC-70	plastic surface mounted package; 3 leads	SOT323				

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

Marking 4.

Product data sheet

Table 5. **Marking codes**

•	
Type number	Marking code ^[1]
PDTC143XE	34
PDTC143XEF	54
PDTC143XK	26
PDTC143XM	E2
PDTC143XS	TC143X
PDTC143XT	*32
PDTC143XU	*53

^{[1] * = -:} made in Hong Kong

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	ı	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	-	50	V
V_{CEO}	collector-emitter voltage	open base	-	-	50	V
V_{EBO}	emitter-base voltage	open collector	-	-	7	V
VI	input voltage					
	positive		-	-	+20	V
	negative		-	-	-7	V
Io	output current		-	-	100	mA
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$				
	SOT416		<u>[1]</u> .	•	150	mW
	SOT490		[1][2]	•	250	mW
	SOT346		<u>[1]</u> .	•	250	mW
	SOT883		[2][3]	-	250	mW
	SOT54		<u>[1]</u> _	-	500	mW
	SOT23		<u>[1]</u> _	•	250	mW
	SOT323		<u>[1]</u> _	-	200	mW
T _{stg}	storage temperature		-	-65	+150	°C
Tj	junction temperature		-	-	150	°C
T _{amb}	ambient temperature		_	-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

^[3] Device mounted on an FR4 PCB with 60 μm copper strip line, standard footprint.

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air					
	SOT416		<u>[1]</u>	-	-	833	K/W
	SOT490		[1][2]	-	-	500	K/W
	SOT346		<u>[1]</u>	-	-	500	K/W
	SOT883		[2][3]	-	-	500	K/W
	SOT54		<u>[1]</u>	-	-	250	K/W
	SOT23		<u>[1]</u>	-	-	500	K/W
	SOT323		[1]	-	-	625	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

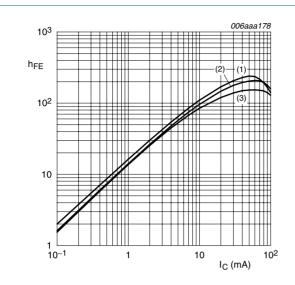
Table 8. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I_{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_{E} = 0 \text{ A}$	-	-	100	nA
I _{CEO}	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$	-	-	1	μΑ
		$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	50	μА
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_C = 0 \text{ A}$	-	-	600	μА
h _{FE}	DC current gain	V_{CE} = 5 V; I_{C} = 10 mA	50	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	-	-	100	mV
$V_{I(off)}$	off-state input voltage	V_{CE} = 5 V; I_{C} = 100 μA	-	-	0.3	V
$V_{I(on)}$	on-state input voltage	V_{CE} = 300 mV; I_{C} = 20 mA	2.5	-	-	V
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		1.7	2.1	2.6	
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	2.5	pF

^[2] Reflow soldering is the only recommended soldering method.

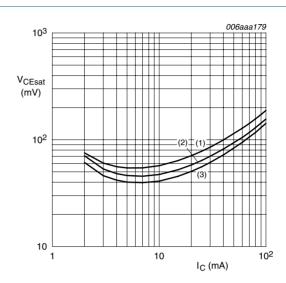
^[3] Device mounted on an FR4 PCB with 60 μ m copper strip line, standard footprint.



(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 1. DC current gain as a function of collector current; typical values

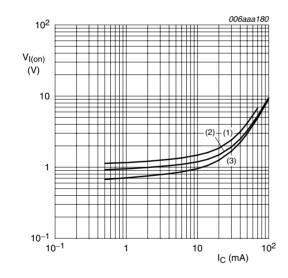


$$I_C/I_B = 20$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values



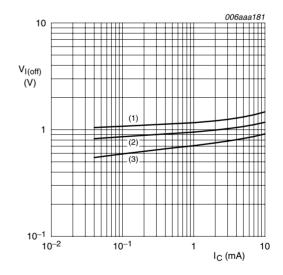
$$V_{CE} = 0.3 \text{ V}$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 3. On-state input voltage as a function of collector current; typical values



$$V_{CE} = 5 V$$

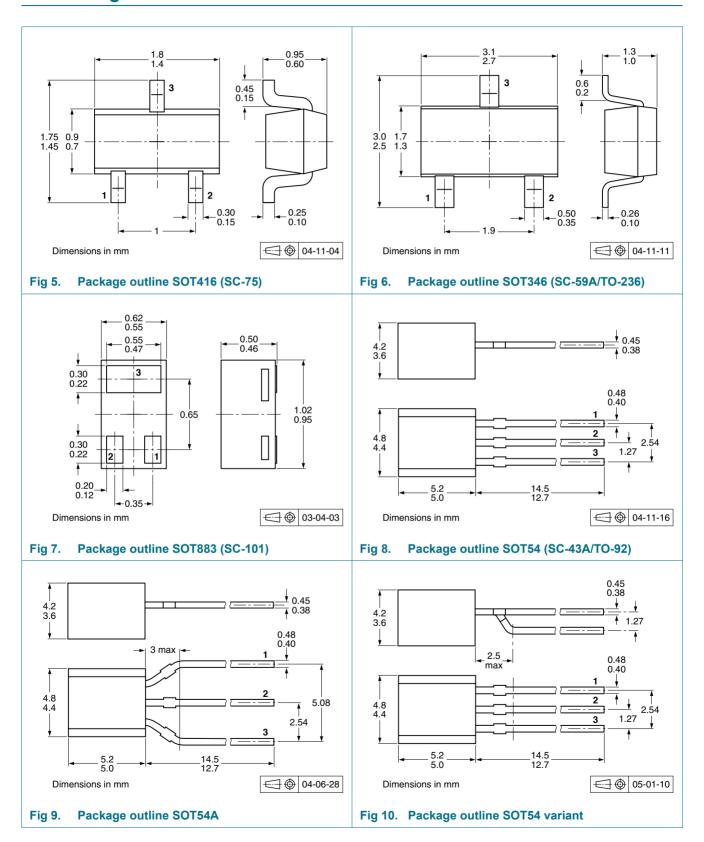
(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 4. Off-state input voltage as a function of collector current; typical values

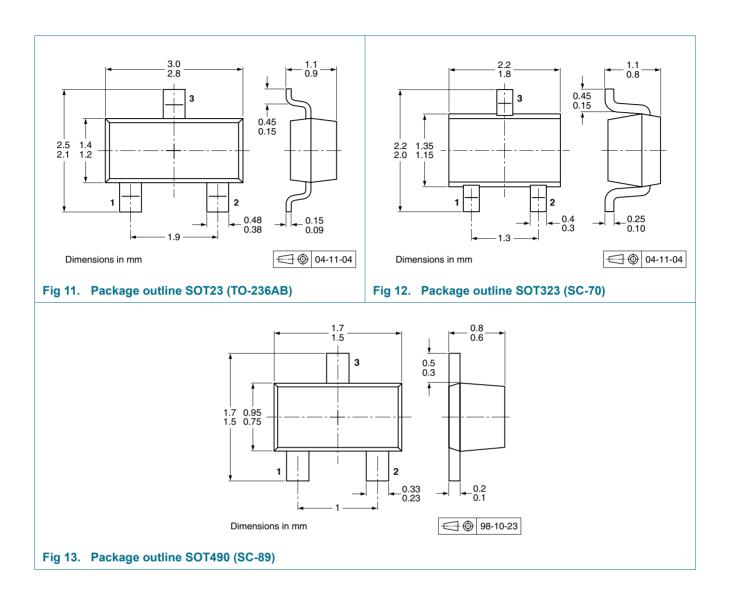
8. Package outline



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Product data sheet

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω



Product data sheet

9 of 12

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω

Packing information

Table 9. **Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity			
			3000	4000	5000	10000
PDTC143XE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-	-135
PDTC143XEF	SOT490	4 mm pitch, 8 mm tape and reel	-	-115	-	-
PDTC143XK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-	-135
PDTC143XM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-	-315
PDTC143XS	SOT54	bulk, straight leads	-	-	-412	-
	SOT54A	tape and reel, wide pitch	-	-	-	-116
		tape ammopack, wide pitch	-	-	-	-126
	SOT54 variant	bulk, delta pinning	-	-	-112	-
PDTC143XT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-	-235
PDTC143XU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-	-135

^[1] For further information and the availability of packing methods, see <u>Section 12</u>.

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω

10. Revision history

Table 10. Revision history

Product data sheet

	,			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTC143X_SER_10	20091116	Product data sheet	-	PDTC143X_SER_9
Modifications:		et was changed to reflect the legal definitions and discla		
PDTC143X_SER_9	20050726	Product data sheet	-	PDTC143X_SERIES_8
PDTC143X_SERIES_8	20040806	Product specification	-	PDTC143X_SERIES_7
PDTC143X_SERIES_7	20040323	Product specification	-	PDTC143X_SERIES_6
PDTC143X_SERIES_6	20040112	Product specification	-	PDTC143X_SERIES_5
PDTC143X_SERIES_5	20031112	Product specification	-	PDTC143X_SERIES_4
PDTC143X_SERIES_4	20030910	Product specification	-	PDTC143X_SERIES_3
PDTC143X_SERIES_3	20030410	Product specification	-	PDTC143XE_2 PDTC143XK_1 PDTC143XT_1
PDTC143XE_2	19990521	Product specification	-	PDTC143XE_1
PDTC143XE_1	19980529	Product specification	-	-
PDTC143XK_1	20020115	Product specification	-	-
PDTC143XT_1	19990420	Product specification	-	-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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For sales office addresses, please send an email to: salesaddresses@nxp.com

PDTC143X series

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω

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